SBAS403D - JUNE 2007 - REVISED MAY 2011

16-Bit, Quad Channel, Ultra-Low Glitch, Voltage Output DIGITAL-TO-ANALOG CONVERTER with 2.5V, 2ppm/°C Internal Reference

Check for Samples: DAC8564

FEATURES

Relative Accuracy: 4LSBGlitch Energy: 0.15nV-s

- Internal Reference:
 - 2.5V Reference Voltage (enabled by default)
 - 0.004% Initial Accuracy (typ)
 - 2ppm/°C Temperature Drift (typ)
 - 5ppm/°C Temperature Drift (max)
 - 20mA Sink/Source Capability
- Power-On Reset to Zero-Scale
- Ultra-Low Power Operation: 1mA at 5V
- Wide Power Supply Range: +2.7V to +5.5V
- 16-Bit Monotonic Over Temperature Range
- Settling Time: 10µs to ±0.003% Full-Scale Range (FSR)
- Low-Power Serial Interface with Schmitt-Triggered Inputs: Up to 50MHz
- On-Chip Output Buffer Amplifier with Rail-to-Rail Operation
- 1.8V to 5.5V Logic Compatibility
- Temperature Range: -40°C to +105°C

APPLICATIONS

- Portable Instrumentation
- Closed-Loop Servo-Control
- Process Control, PLCs
- Data Acquisition Systems
- Programmable Attenuation
- PC Peripherals

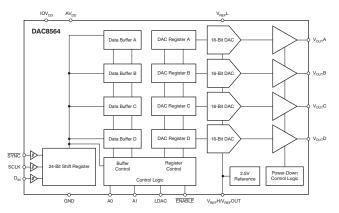
RELATED DEVICES	16-BIT	14-BIT	12-BIT
Pin and Functionally Compatible	DAC8564	DAC8164	DAC7564
Functionally Compatible	DAC8565	DAC8165	DAC7565

DESCRIPTION

The DAC8564 is a low-power, voltage-output, four-channel, 16-bit digital-to-analog converter (DAC). The device includes a 2.5V, 2ppm/°C internal reference (enabled by default), giving a full-scale output voltage range of 2.5V. The internal reference has an initial accuracy of 0.004% and can source up to 20mA at the V_{REF}H/V_{REF}OUT pin. The device is monotonic, provides very good linearity, and minimizes undesired code-to-code transient voltages (glitch). The DAC8564 uses a versatile 3-wire serial interface that operates at clock rates up to 50MHz. The interface is compatible with standard SPI™, QSPI™, Microwire™, and digital signal processor (DSP) interfaces.

The DAC8564 incorporates a power-on-reset circuit that ensures the DAC output powers up at zero-scale and remains there until a valid code is written to the device. The device contains a power-down feature, accessed over the serial interface, that reduces the current consumption of the device to 1.3µA at 5V. Power consumption is 2.9mW at 3V, reducing to 1.5µW in power-down mode. The low-power consumption, internal reference, and small footprint make this device ideal for portable, battery-operated equipment.

The DAC8564 is drop-in and functionally compatible with the DAC7564 and DAC8164, and functionally compatible with the DAC7565, DAC8165, and DAC8565. All these devices are available in a TSSOP-16 package.



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION(1)

PRODUCT	RELATIVE ACCURACY (LSB)	DIFFERENTIAL NONLINEARITY (LSB)	REFERENCE DRIFT (ppm/°C)	PACKAGE- LEAD	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING
DAC8564A	±12	±1	25	TSSOP-16	PW	-40°C to +105°C	DAC8564
DAC8564B	±8	±1	25	TSSOP-16	PW	-40°C to +105°C	DAC8564B
DAC8564C	±12	±1	5	TSSOP-16	PW	-40°C to +105°C	DAC8564
DAC8564D	±8	±1	5	TSSOP-16	PW	-40°C to +105°C	DAC8564D

⁽¹⁾ For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

ABSOLUTE MAXIMUM RATINGS(1)

Over operating free-air temperature range (unless otherwise noted).

$\begin{array}{cccccccccccccccccccccccccccccccccccc$	UNIT
$\begin{array}{c} V_{OUT} \text{ to GND} & -0.3 \text{ to } + V_{DD} + 0.3 \\ V_{REF} \text{ to GND} & -0.3 \text{ to } + V_{DD} + 0.3 \\ \end{array}$ $\begin{array}{c} Operating \text{ temperature range} & -40 \text{ to } +125 \\ Storage \text{ temperature range} & -65 \text{ to } +150 \\ Junction \text{ temperature range} & +150 \\ \end{array}$ $\begin{array}{c} Operating \text{ temperature range} & -65 \text{ to } +150 \\ Operating temperature r$	V
V_{REF} to GND -0.3 to $+V_{DD} + 0.3$ Operating temperature range -40 to $+125$ Storage temperature range -65 to $+150$ Junction temperature range (T_J max) $+150$ Power dissipation $(T_J$ max $-T_A)/\theta_{JA}$	V
Operating temperature range -40 to +125 Storage temperature range -65 to +150 Junction temperature range (T _J max) +150 Power dissipation (T _J max - T _A)/θ _{JA}	V
Storage temperature range $-65 \text{ to } +150$ Junction temperature range (T _J max) $+150$ Power dissipation $(T_J \max - T_A)/\theta_{JA}$	V
Junction temperature range (T _J max) +150 Power dissipation $(T_J \max - T_A)/\theta_{JA}$	°C
Power dissipation $(T_J \max - T_A)/\theta_{JA}$	°C
	°C
Thermal impedance, θ_{JA} +118	W
	°C/W
Thermal impedance, θ_{JC} +29	°C/W
Human body model (HBM) 4000	V
ESD rating Charged device model (CDM) 1500	V

⁽¹⁾ Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods may affect device reliability.



ELECTRICAL CHARACTERISTICS

At AV_{DD} = 2.7V to 5.5V and -40° C to +105°C range (unless otherwise noted).

			DA	AC8564		
PARAMETER	TEST	CONDITIONS	MIN	TYP MAX		UNIT
STATIC PERFORMANCE ⁽¹⁾		<u>'</u>				
Resolution			16			Bits
	Measured by the line	DAC8564A, DAC8564C		±4	±12	LSB
Relative accuracy	passing through codes 485 and 64714	DAC8564B, DAC8564D		±4	±8	LSB
Differential nonlinearity	16-bit monotonic			±0.5	±1	LSB
Offset error				±5	±8	mV
Offset error drift	Measured by the line p	assing through codes 485 and		±1		μV/°C
Full-scale error	64714			±0.2	±0.5	% of FSR
Gain error				±0.05	±0.2	% of FSR
O-in to	AV _{DD} = 5V			±1		ppm of
Gain temperature coefficient	$AV_{DD} = 2.7V$			±2		FSR/°C
PSRR Power-supply rejectio	n ratio Output unloaded			1		mV/V
OUTPUT CHARACTERISTICS(2)					'	
Output voltage range			0		V_{REF}	V
Output voltage settling time	To ±0.003% FSR, 0200 0pF < C _L < 200pF	Oh to FD00h, $R_L = 2k\Omega$,		8	10	μs
	$R_L = 2k\Omega$, $C_L = 500pF$			12		
Slew rate				2.2		V/µs
	R _L = ∞			470		_
Capacitive load stability	$R_L = 2k\Omega$			1000		pF
Code change glitch impulse	1LSB change around n	najor carry		0.15		nV-s
Digital feedthrough	SCLK toggling, SYNC	high		0.15		nV-s
Channel-to-channel dc crosstalk	Full-scale swing on adj	acent channel		0.25		LSB
Channel-to-channel ac crosstalk	1kHz full-scale sine wa	ve, outputs unloaded		-100		dB
DC output impedance	At mid-code input			1		Ω
Short-circuit current				50		mA
Davida va tima	Coming out of power-d	own mode, AV _{DD} = 5V		2.5		
Power-up time	Coming out of power-d	own mode, AV _{DD} = 3V		5		μs
AC PERFORMANCE ⁽²⁾	·					
SNR				90		dB
THD	T _A = +25°C, BW = 20k	Hz, V _{DD} = 5V, f _{OUT} = 1kHz.		–77		dB
SFDR		noved for SNR calculation.		78		dB
SINAD				77		dB
DAC output noise density	$T_A = +25^{\circ}C$, at mid-cod	le input, f _{OUT} = 1kHz		120		nV/√ Hz
DAC output noise	$T_A = +25^{\circ}C$, at mid-coo	de input, 0.1Hz to 10Hz		6		μV_{PP}
REFERENCE	·					
Internal reference current concumption	AV _{DD} = 5.5V			360		μA
Internal reference current consumption	$AV_{DD} = 3.6V$			348		μΑ
External reference current	External V _{REF} = 2.5V, ii all four channels active	f internal reference is disabled,		80		μA
Reference input range V _{REF} H voltage	V _{REF} L < V _{REF} H, AV _{DD} -	- (V _{REF} H + V _{REF} L) /2 > 1.2V	0		AV_{DD}	V
Reference input range V _{REF} L voltage		- (V _{REF} H + V _{REF} L) /2 > 1.2V	0		AV _{DD} /2	V
Reference input impedance				31		kΩ

⁽¹⁾ Linearity calculated using a reduced code range of 485 to 64714; output unloaded.(2) Ensured by design or characterization; not production tested.



ELECTRICAL CHARACTERISTICS (continued)

At $AV_{DD} = 2.7V$ to 5.5V and -40° C to $+105^{\circ}$ C range (unless otherwise noted).

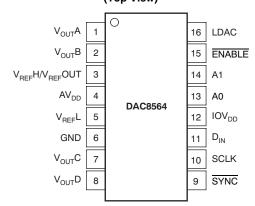
			D	AC8564				
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
REFERENCE	OUTPUT							
Output voltage	•	$T_A = +25^{\circ}C$	2.4975	2.5	2.5025	V		
nitial accuracy	1	$T_A = +25^{\circ}C$	-0.1	±0.004	0.1	%		
0.4414		DAC8564A, DAC8564B ⁽³⁾		5	25	/00		
Output voltage	temperature drift	DAC8564C, DAC8564D ⁽⁴⁾		2 5		ppm/°C		
Output voltage	noise	f = 0.1Hz to 10Hz		12		μV_{PP}		
		$T_A = +25^{\circ}C$, $f = 1MHz$, $C_L = 0\mu F$		50				
Output voltage high-frequenc	noise density	$T_A = +25^{\circ}C$, $f = 1MHz$, $C_L = 1\mu F$		20		nV/√Hz		
(mgm moquomo	y 110100)	$T_A = +25^{\circ}C$, $f = 1MHz$, $C_L = 4\mu F$		16				
Load regulation	n, sourcing ⁽⁵⁾	T _A = +25°C		30		μV/mA		
_oad regulation	n, sinking ⁽⁵⁾	T _A = +25°C		15		μV/mA		
Output current	load capability (6)			±20		mA		
Line regulation	1	T _A = +25°C		10		μV/V		
Long-term stat	oility/drift (aging) ⁽⁵⁾	T _A = +25°C, time = 0 to 1900 hours		50		ppm		
		First cycle		100				
Thermal hyste	resis "	Additional cycles		25		ppm		
LOGIC INPUT	S ⁽⁶⁾		<u> </u>					
Input current				±1		μA		
	1	2.7V ≤ IOV _{DD} ≤ 5.5V		0.3	3 × IOV _{DD}	V		
V _{IN} L	Logic input LOW voltage	1.8V ≤ IOV _{DD} ≤ 2.7V		0.	1 × IOV _{DD}	v		
	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	2.7V ≤ IOV _{DD} ≤ 5.5V 0.7 × IOV _{DD}				V		
V _{IN} H	Logic input HIGH voltage	1.8V ≤ IOV _{DD} ≤ 2.7V	0.95 × IOV _{DD}	0.95 × IOV _{DD}				
Pin capacitano	e				3	pF		
POWER REQU	UIREMENTS		·					
AV _{DD}			2.7		5.5	V		
IOV _{DD}			1.8		5.5	V		
IOI _{DD} (6)				10	20	μA		
	Normal mode	$AV_{DD} = IOV_{DD} = 3.6V \text{ to } 5.5V$ $V_{IN}H = IOV_{DD} \text{ and } V_{IN}L = GND$		1	1.6	A		
I _{DD} ⁽⁷⁾	Normal mode	$\begin{array}{l} {\rm AV_{DD} = IOV_{DD} = 2.7V~to~3.6V} \\ {\rm V_{IN}H = IOV_{DD}~and~V_{IN}L = GND} \end{array}$		0.95	1.5	mA		
טטי	All power-down modes	$\begin{array}{l} {\rm AV_{DD} = IOV_{DD} = 3.6V~to~5.5V} \\ {\rm V_{IN}H = IOV_{DD}~and~V_{IN}L = GND} \end{array}$		1.3	3.5	пΔ		
	7 power down modes	$AV_{DD} = IOV_{DD} = 2.7V$ to $3.6V$ $V_{IN}H = IOV_{DD}$ and $V_{IN}L = GND$		0.5	2.5	μΑ		
	Normal mode	$AV_{DD} = IOV_{DD} = 3.6V$ to $5.5V$ $V_{IN}H = IOV_{DD}$ and $V_{IN}L = GND$		3.6	8.8	mW		
Power	Tromai mode	$\begin{array}{l} {\sf AV_{DD} = IOV_{DD} = 2.7V \ to \ 3.6V} \\ {\sf V_{IN} H = IOV_{DD} \ and \ V_{IN} L = GND} \end{array}$		2.6	2.6 5.4			
Dissipation (7)	All power-down modes	$\begin{array}{l} {\rm AV_{DD} = IOV_{DD} = 3.6V~to~5.5V} \\ {\rm V_{IN}H = IOV_{DD}~and~V_{IN}L = GND} \end{array}$		4.7 19				
	$AV_{DD} = IOV_{DD} = 2.7V \text{ to } 3.6V$ $V_{IN}H = IOV_{DD} \text{ and } V_{IN}L = GND$			1.4 9				
TEMPERATUR	RE RANGE							
Specified perfo	ormance		-40		+105	°C		

- (3) Reference is trimmed and tested at room temperature, and is characterized from -40°C to +120°C.
- (4) Reference is trimmed and tested at two temperatures (+25°C and +105°C), and is characterized from -40°C to +120°C.
- (5) Explained in more detail in the *Application Information* section of this data sheet.
- (6) Ensured by design or characterization; not production tested.
- (7) Input code = 32768, reference current included, no load.



PIN CONFIGURATIONS

PW PACKAGE TSSOP-16 (Top View)

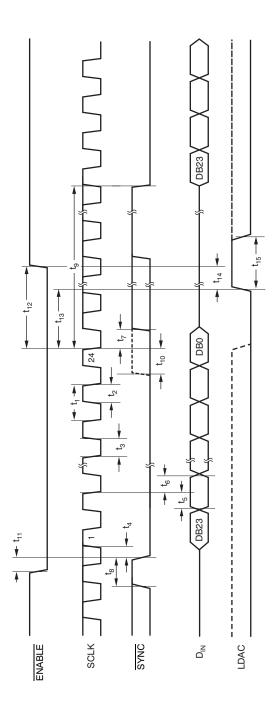


PIN DESCRIPTIONS

PIN	NAME	DESCRIPTION
1	V _{OUT} A	Analog output voltage from DAC A
2	$V_{OUT}B$	Analog output voltage from DAC B
3	V _{REF} H/ V _{REF} OUT	Positive reference input / reference output 2.5V if internal reference used.
4	AV_DD	Power-supply input, 2.7V to 5.5V
5	$V_{REF}L$	Negative reference input
6	GND	Ground reference point for all circuitry on the part
7	$V_{OUT}C$	Analog output voltage from DAC C
8	$V_{OUT}D$	Analog output voltage from DAC D
9	SYNC	Level-triggered control input (active low). This input is the frame synchronization signal for the input data. When \$\overline{SYNC}\$ goes low, it enables the input shift register, and data are sampled on subsequent falling clock edges. The DAC output updates following the 24th clock. If \$\overline{SYNC}\$ is taken high before the 24th clock edge, the rising edge of \$\overline{SYNC}\$ acts as an interrupt, and the write sequence is ignored by the DAC8564. Schmitt-Trigger logic input.
10	SCLK	Serial clock input. Data can be transferred at rates up to 50MHz. Schmitt-Trigger logic input.
11	D_IN	Serial data input. Data are clocked into the 24-bit input shift register on each falling edge of the serial clock input. Schmitt-Trigger logic input.
12	IOV_{DD}	Digital input-output power supply
13	A0	Address 0—sets device address; see Table 5.
14	A1	Address 1—sets device address; see Table 5.
15	ENABLE	The enable pin (active low) connects the SPI interface to the serial port
16	LDAC	Load DACs; rising edge triggered, loads all DAC registers



SERIAL WRITE OPERATION



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TIMING REQUIREMENTS(1) (2)

At $AV_{DD} = IOV_{DD} = 2.7V$ to 5.5V and $-40^{\circ}C$ to $+105^{\circ}C$ range (unless otherwise noted).

			D	DAC8564				
	PARAMETER	TEST CONDITIONS	MIN	TYP MA	UNIT			
t ₁ (3)	CCL K avalatima	$IOV_{DD} = AV_{DD} = 2.7V$ to 3.6V	40		20			
τ ₁ (σ)	SCLK cycle time	$IOV_{DD} = AV_{DD} = 3.6V \text{ to } 5.5V$	20		ns			
	0017/110117	$IOV_{DD} = AV_{DD} = 2.7V \text{ to } 3.6V$	20					
t ₂	SCLK HIGH time	$IOV_{DD} = AV_{DD} = 3.6V \text{ to } 5.5V$	10		ns			
	CCLIV LOW times	$IOV_{DD} = AV_{DD} = 2.7V$ to 3.6V	20					
t ₃	SCLK LOW time	$IOV_{DD} = AV_{DD} = 3.6V$ to 5.5V	10		ns			
	CVAIC to CCLIV vision and an activa time.	$IOV_{DD} = AV_{DD} = 2.7V$ to 3.6V	0					
t ₄	SYNC to SCLK rising edge setup time	$IOV_{DD} = AV_{DD} = 3.6V \text{ to } 5.5V$	0		ns			
	Data action time	$IOV_{DD} = AV_{DD} = 2.7V$ to 3.6V	5					
t ₅	Data setup time	$IOV_{DD} = AV_{DD} = 3.6V \text{ to } 5.5V$	5		ns			
	Data hold time	$IOV_{DD} = AV_{DD} = 2.7V$ to 3.6V	4.5		20			
6	Data hold time	$IOV_{DD} = AV_{DD} = 3.6V$ to 5.5V	4.5		ns			
	CCLI/ falling adds to CVNC vising adds	$IOV_{DD} = AV_{DD} = 2.7V$ to 3.6V	0		20			
7	SCLK falling edge to SYNC rising edge	$IOV_{DD} = AV_{DD} = 3.6V \text{ to } 5.5V$	0		ns			
	Minimum SYNC HIGH time	$IOV_{DD} = AV_{DD} = 2.7V$ to 3.6V	40		20			
8	Willimum Stric high time	$IOV_{DD} = AV_{DD} = 3.6V$ to 5.5V	20		ns			
	OAN COLIC falling a day to CVNO falling a day	$IOV_{DD} = AV_{DD} = 2.7V$ to 3.6V	130					
9	24th SCLK falling edge to SYNC falling edge	$IOV_{DD} = AV_{DD} = 3.6V \text{ to } 5.5V$	130		ns			
	SYNC rising edge to 24th SCLK falling edge	$IOV_{DD} = AV_{DD} = 2.7V$ to 3.6V	15		20			
10	(for successful SYNC interrupt)	$IOV_{DD} = AV_{DD} = 3.6V$ to 5.5V	15		ns			
	ENADLE follog adge to CVNC follog adge	$IOV_{DD} = AV_{DD} = 2.7V$ to 3.6V	15		20			
11	ENABLE falling edge to SYNC falling edge	$IOV_{DD} = AV_{DD} = 3.6V$ to 5.5V	15		ns			
	OAN COLK falling adapt to FNARIE signing adap	$IOV_{DD} = AV_{DD} = 2.7V$ to 3.6V	10					
12	24th SCLK falling edge to ENABLE rising edge	$IOV_{DD} = AV_{DD} = 3.6V \text{ to } 5.5V$	10		ns			
	24th CCLK follow adds to LDAC vising adds	$IOV_{DD} = AV_{DD} = 2.7V$ to 3.6V	50		20			
13	24th SCLK falling edge to LDAC rising edge	$IOV_{DD} = AV_{DD} = 3.6V$ to 5.5V	50		ns			
	LDAC rising edge to ENABLE rising edge	$IOV_{DD} = AV_{DD} = 2.7V \text{ to } 3.6V$	10					
^t 14	LDAC IISING edge to ENABLE TISING edge	$IOV_{DD} = AV_{DD} = 3.6V \text{ to } 5.5V$	10		ns			
	L DAC LIICH time	$IOV_{DD} = AV_{DD} = 2.7V$ to 3.6V						
15	LDAC HIGH time	$IOV_{DD} = AV_{DD} = 3.6V \text{ to } 5.5V$	10		ns			

 ⁽¹⁾ All input signals are specified with t_R = t_F = 3ns (10% to 90% of V_{DD}) and timed from a voltage level of (V_{IL} + V_{IH})/2.
 (2) See the Serial Write Operation timing diagram.
 (3) Maximum SCLK frequency is 50MHz at IOV_{DD} = V_{DD} = 3.6V to 5.5V and 25MHz at IOV_{DD} = AV_{DD} = 2.7V to 3.6V.



TYPICAL CHARACTERISTICS: Internal Reference

At $T_A = +25$ °C, unless otherwise noted.

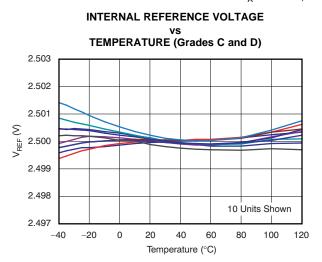


Figure 1.

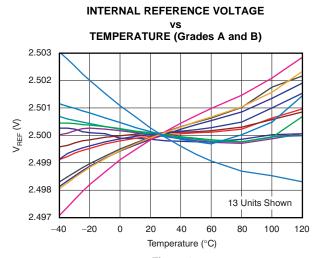


Figure 2.

REFERENCE OUTPUT TEMPERATURE DRIFT (-40°C to +120°C, Grades C and D)

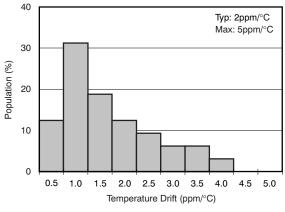


Figure 3.

REFERENCE OUTPUT TEMPERATURE DRIFT (-40°C to +120°, Grades A and B) Typ: 5ppm/°C

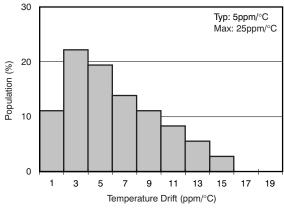


Figure 4.

REFERENCE OUTPUT TEMPERATURE DRIFT (0°C to +120°C, Grades C and D)

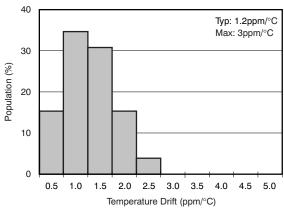


Figure 5.

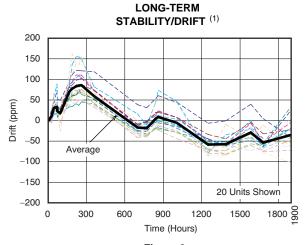


Figure 6.

Explained in more detail in the Application Information section of this data sheet. (1)



TYPICAL CHARACTERISTICS: Internal Reference (continued)

At $T_A = +25$ °C, unless otherwise noted.



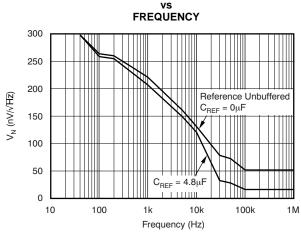


Figure 7.

INTERNAL REFERENCE NOISE 0.1Hz TO 10Hz

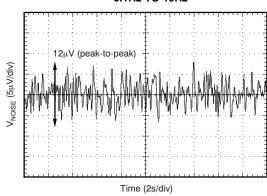


Figure 8.

INTERNAL REFERENCE VOLTAGE vs LOAD CURRENT (Grades C and D)

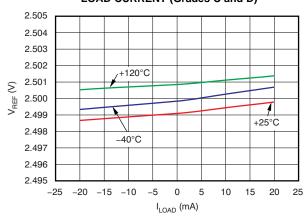


Figure 9.

INTERNAL REFERENCE VOLTAGE vs LOAD CURRENT (Grades A and B)

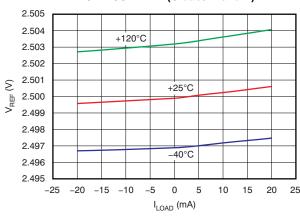


Figure 10.

INTERNAL REFERENCE VOLTAGE vs SUPPLY VOLTAGE (Grades C and D)

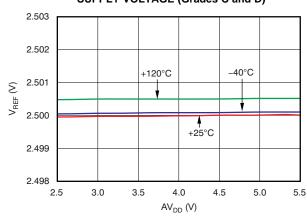


Figure 11.

INTERNAL REFERENCE VOLTAGE vs SUPPLY VOLTAGE (Grades A and B)

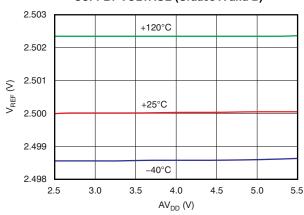


Figure 12.



TYPICAL CHARACTERISTICS: DAC at $AV_{DD} = 5V$

At $T_A = +25$ °C, external reference used, DAC output not loaded, and all DAC codes in straight binary data format, unless otherwise noted.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (-40°C)

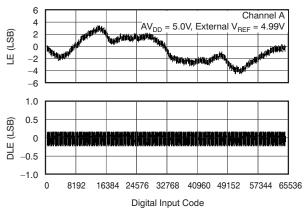


Figure 13.

DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE (-40°C)

LINEARITY ERROR AND

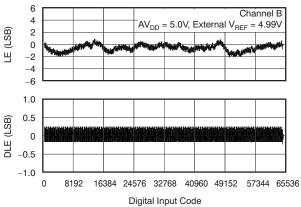


Figure 14.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (-40°C)

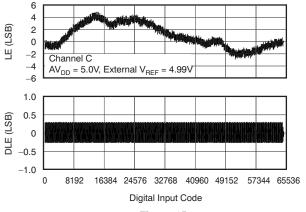


Figure 15.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (-40°C)

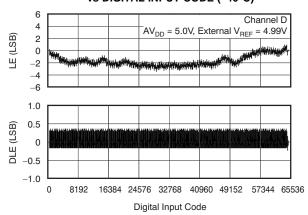


Figure 16.



At $T_A = +25^{\circ}C$, external reference used, DAC output not loaded, and all DAC codes in straight binary data format, unless otherwise noted.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (+25°C)

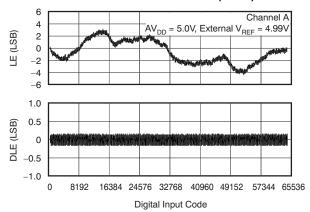


Figure 17.

DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE (+25°C)

LINEARITY ERROR AND

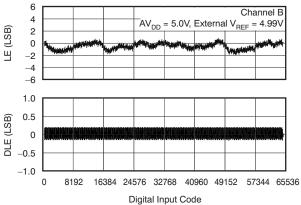


Figure 18.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (+25°C)

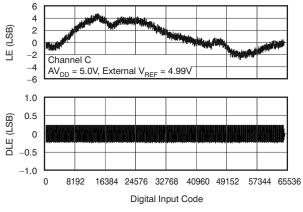


Figure 19.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (+25°C)

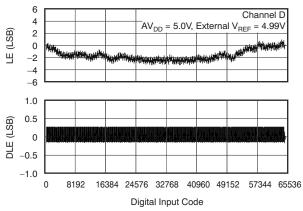


Figure 20.



At $T_A = +25^{\circ}C$, external reference used, DAC output not loaded, and all DAC codes in straight binary data format, unless otherwise noted.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (+105°C)

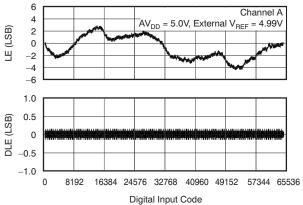


Figure 21.

DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE (+105°C)

LINEARITY ERROR AND

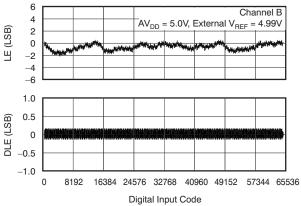


Figure 22.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (+105°C)

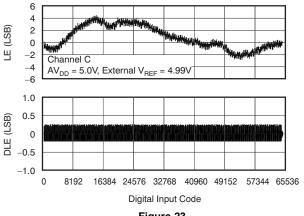


Figure 23.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (+105°C)

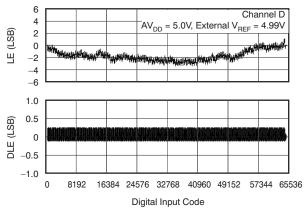
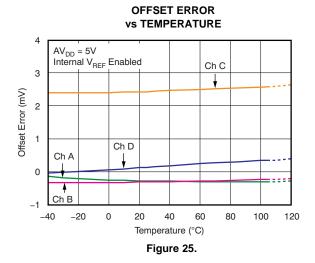
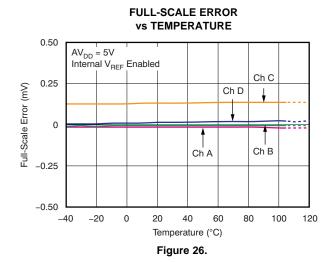


Figure 24.

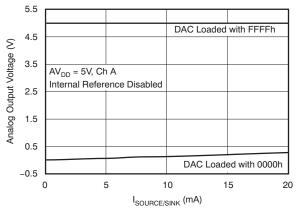


At $T_A = +25^{\circ}C$, external reference used, DAC output not loaded, and all DAC codes in straight binary data format, unless otherwise noted.









SOURCE AND SINK CURRENT CAPABILITY

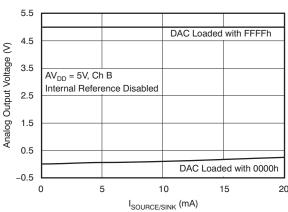
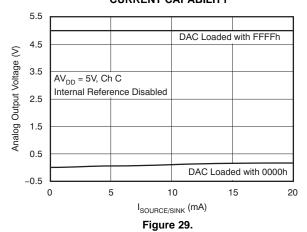


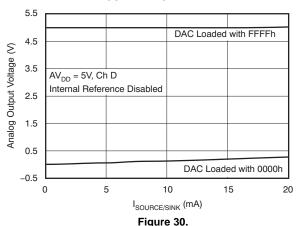
Figure 27.

SOURCE AND SINK
CURRENT CAPABILITY



SOURCE AND SINK
CURRENT CAPABILITY

Figure 28.



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At $T_A = +25^{\circ}C$, external reference used, DAC output not loaded, and all DAC codes in straight binary data format, unless otherwise noted.



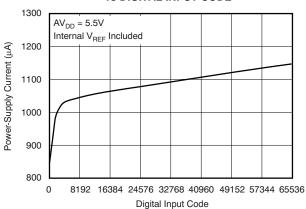


Figure 31.

POWER-SUPPLY CURRENT vs TEMPERATURE

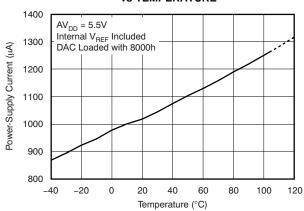


Figure 32.

POWER-SUPPLY CURRENT vs POWER-SUPPLY VOLTAGE

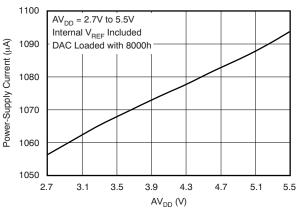


Figure 33.

POWER-DOWN CURRENT vs POWER-SUPPLY VOLTAGE

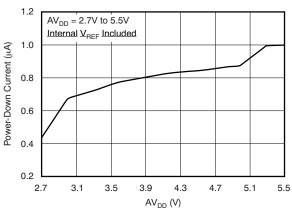
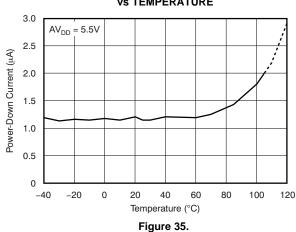


Figure 34.

POWER-DOWN CURRENT vs TEMPERATURE



POWER-SUPPLY CURRENT vs LOGIC INPUT VOLTAGE

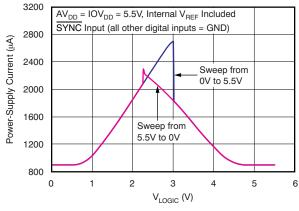


Figure 36.

THD (dB)



TYPICAL CHARACTERISTICS: DAC at AV_{DD} = 5V (continued)

At T_A = +25°C, external reference used, DAC output not loaded, and all DAC codes in straight binary data format, unless otherwise noted.

TOTAL HARMONIC DISTORTION vs OUTPUT FREQUENCY -40 AV_{DD} = 5V, External V_{REF} = 4.9V, Ch A -1dB FSR Digital Input, f_S = 225kSPS -50 Measurement Bandwidth = 20kHz -60 -70 THD -80 3rd Harmonic -90 2nd Harmonic -100 4

Figure 37.

 f_{OUT} (kHz)

TOTAL HARMONIC DISTORTION vs OUTPUT FREQUENCY

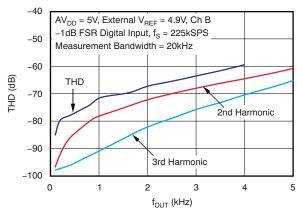


Figure 38.

TOTAL HARMONIC DISTORTION vs OUTPUT FREQUENCY

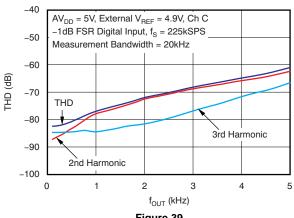


Figure 39.

TOTAL HARMONIC DISTORTION vs OUTPUT FREQUENCY

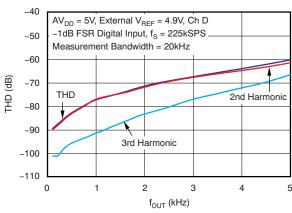


Figure 40.

POWER-SUPPLY CURRENT HISTOGRAM

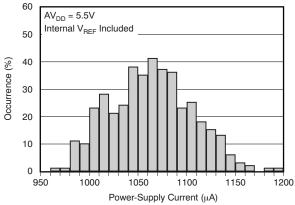
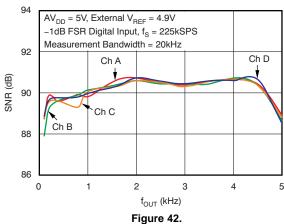


Figure 41.



At T_A = +25°C, external reference used, DAC output not loaded, and all DAC codes in straight binary data format, unless otherwise noted.

SIGNAL-TO-NOISE RATIO **vs OUTPUT FREQUENCY**



POWER SPECTRAL DENSITY

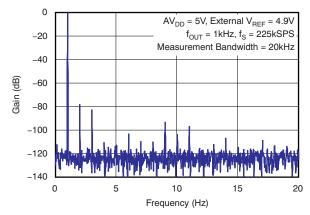
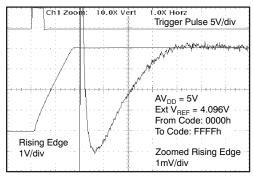


Figure 43.

FULL-SCALE SETTLING TIME: 5V RISING EDGE



Time (2µs/div)

FULL-SCALE SETTLING TIME: 5V FALLING EDGE

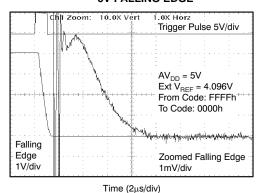


Figure 45.

Figure 44.

HALF-SCALE SETTLING TIME: **5V RISING EDGE**

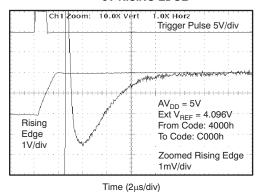
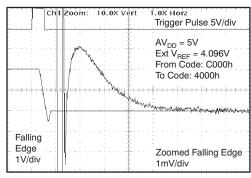


Figure 46.

HALF-SCALE SETTLING TIME: **5V FALLING EDGE**



Time (2µs/div)

Figure 47.



At T_A = +25°C, external reference used, DAC output not loaded, and all DAC codes in straight binary data format, unless otherwise noted.

GLITCH ENERGY: 5V, 1LSB STEP, RISING EDGE

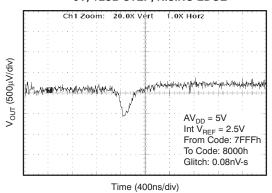


Figure 48.

GLITCH ENERGY: 5V, 16LSB STEP, RISING EDGE

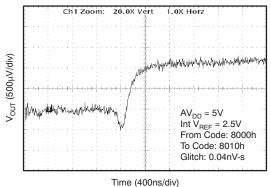


Figure 50.

GLITCH ENERGY:

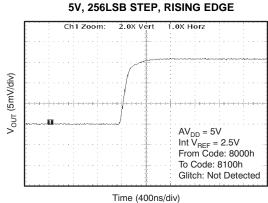
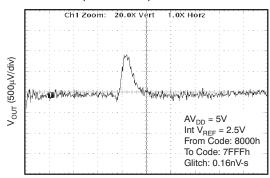


Figure 52.

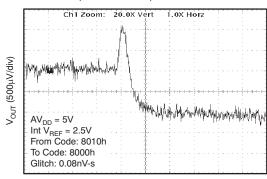
GLITCH ENERGY: 5V, 1LSB STEP, FALLING EDGE



Time (400ns/div)

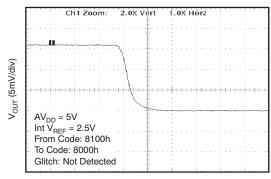
Figure 49.

GLITCH ENERGY: 5V, 16LSB STEP, FALLING EDGE



Time (400ns/div) Figure 51.

GLITCH ENERGY: 5V, 256LSB STEP, FALLING EDGE

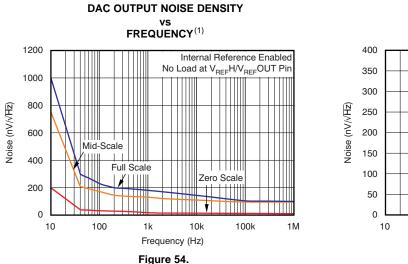


Time (400ns/div)

Figure 53.



At $T_A = +25$ °C, external reference used, DAC output not loaded, and all DAC codes in straight binary data format, unless otherwise noted.



THAT IN THE PROPERTY (2)

PROPERTY (2)

DAC = Full-Scale Internal Reference Enabled 4.8µF versus No Load at V_{REF}H/V_{REF}OUT Pin 200 No Load on Reference 150 No Load on Reference 150 On Refere

Frequency (Hz)

10k

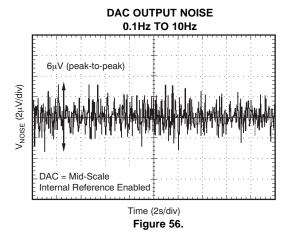
100k

1M

DAC OUTPUT NOISE DENSITY

Figure 55.

100

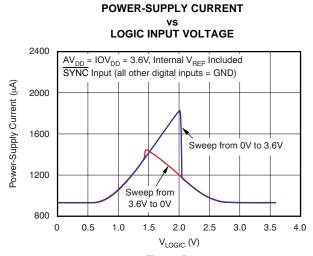


- (1) Explained in more detail in the Application Information section of this data sheet.
- (2) See the Application Information section for more information.



TYPICAL CHARACTERISTICS: DAC at AV_{DD} = 3.6V

At $T_A = +25$ °C, internal reference used, and DAC output not loaded, all DAC codes in straight binary data format, unless otherwise noted



1400 AV_{DD} = 3.6V Internal V_{REF} Included DAC Loaded with 8000h 1200 DAC Loaded with 8000h 900 900

POWER-SUPPLY CURRENT

Figure 57.

Temperature (°C) **Figure 58.**

40

60

80

100

120

POWER-SUPPLY CURRENT HISTOGRAM $AV_{DD} = 3.6V$ Internal V_{REF} Included 60 Occurrence (%) 40 20 1200 900 950 1000 1150 1050 Power-Supply Current (μ A) Figure 59.

800

-40

-20

0



TYPICAL CHARACTERISTICS: DAC at AV_{DD} = 2.7V

At $T_A = +25$ °C, internal reference used, and DAC output not loaded, all DAC codes in straight binary data format, unless otherwise noted

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (-40°C)

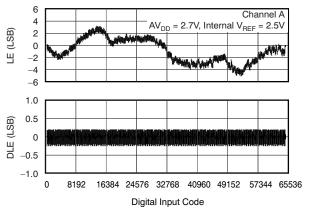


Figure 60.

DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE (-40°C)

LINEARITY ERROR AND

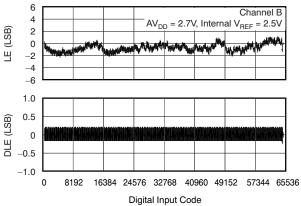


Figure 61.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (-40°C)

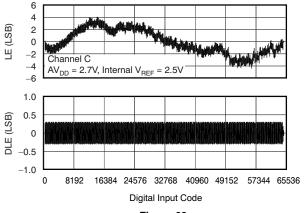


Figure 62.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (-40°C)

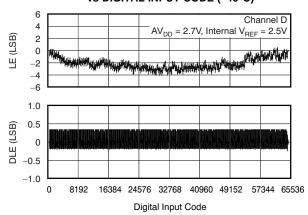


Figure 63.



At T_A = +25°C, internal reference used, and DAC output not loaded, all DAC codes in straight binary data format, unless otherwise noted

LINEARITY ERROR AND **DIFFERENTIAL LINEARITY ERROR** vs DIGITAL INPUT CODE (+25°C)

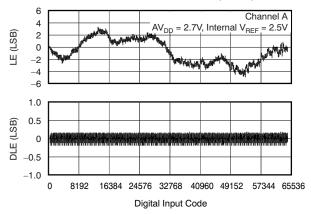


Figure 64.

DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE (+25°C)

LINEARITY ERROR AND

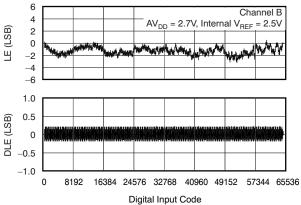


Figure 65.

LINEARITY ERROR AND **DIFFERENTIAL LINEARITY ERROR** vs DIGITAL INPUT CODE (+25°C)

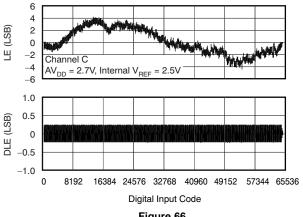


Figure 66.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE (+25°C)

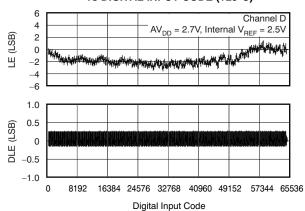


Figure 67.



TYPICAL CHARACTERISTICS: DAC at $AV_{DD} = 2.7V$ (continued)

At T_A = +25°C, internal reference used, and DAC output not loaded, all DAC codes in straight binary data format, unless otherwise noted

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (+105°C)

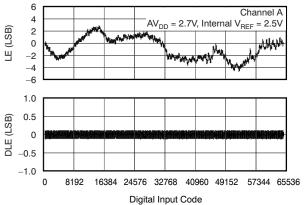


Figure 68.

DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE (+105°C)

LINEARITY ERROR AND

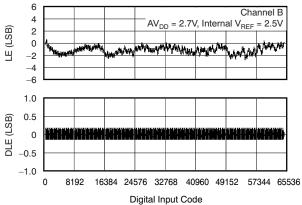


Figure 69.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (+105°C)

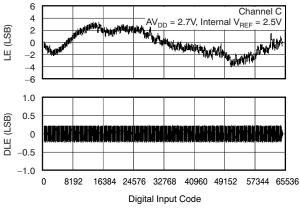


Figure 70.

LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE (+105°C)

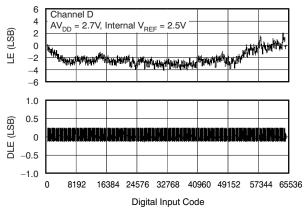
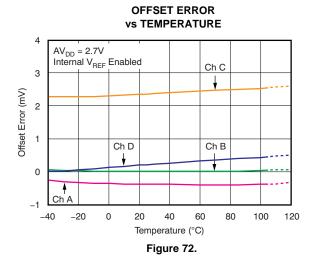
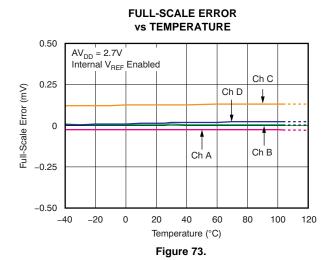


Figure 71.

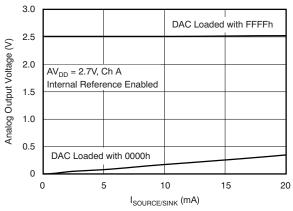


At T_A = +25°C, internal reference used, and DAC output not loaded, all DAC codes in straight binary data format, unless otherwise noted









SOURCE AND SINK
CURRENT CAPABILITY

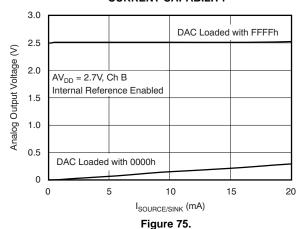
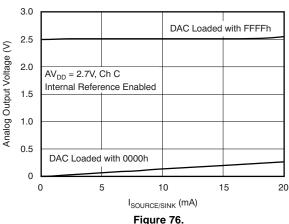


Figure 74.





SOURCE AND SINK
CURRENT CAPABILITY

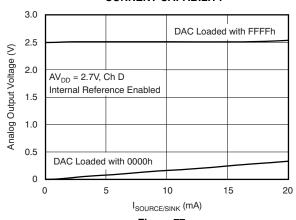


Figure 77.



At $T_A = +25^{\circ}C$, internal reference used, and DAC output not loaded, all DAC codes in straight binary data format, unless otherwise noted

POWER-SUPPLY CURRENT vs DIGITAL INPUT CODE

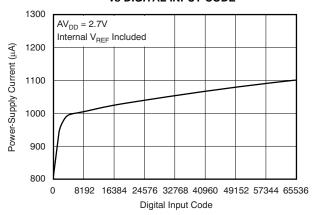


Figure 78.

FULL-SCALE SETTLING TIME: 2.7V RISING EDGE

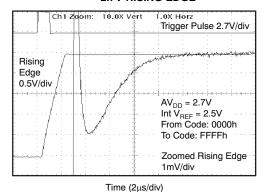


Figure 80.

HALF-SCALE SETTLING TIME: 2.7V RISING EDGE

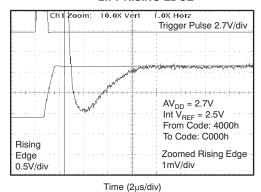


Figure 82.

POWER-SUPPLY CURRENT VS LOGIC INPUT VOLTAGE

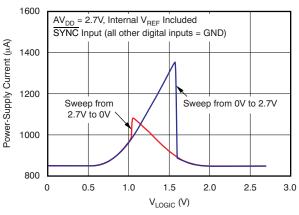


Figure 79.

FULL-SCALE SETTLING TIME: 2.7V FALLING EDGE

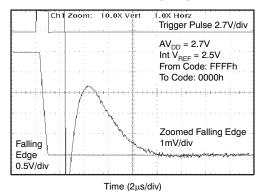
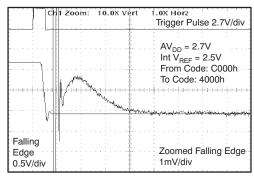


Figure 81.

HALF-SCALE SETTLING TIME: 2.7V FALLING EDGE



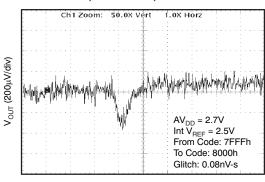
Time (2µs/div)

Figure 83.



At $T_A = +25^{\circ}C$, internal reference used, and DAC output not loaded, all DAC codes in straight binary data format, unless otherwise noted

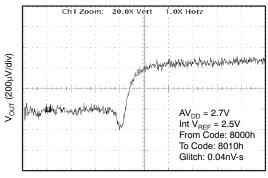
GLITCH ENERGY: 2.7V, 1LSB STEP, RISING EDGE



Time (400ns/div)

Figure 84.

GLITCH ENERGY: 2.7V, 16LSB STEP, RISING EDGE



Time (400ns/div)

Figure 86.

GLITCH ENERGY: 2.7V, 256LSB STEP, RISING EDGE

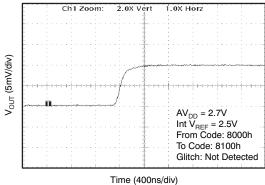
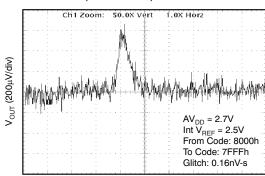


Figure 88.

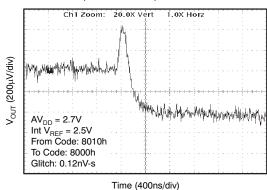
GLITCH ENERGY: 2.7V, 1LSB STEP, FALLING EDGE



Time (400ns/div)

Figure 85.

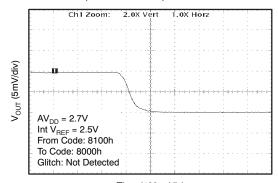
GLITCH ENERGY: 2.7V, 16LSB STEP, FALLING EDGE



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Figure 87.

GLITCH ENERGY: 2.7V, 256LSB STEP, FALLING EDGE

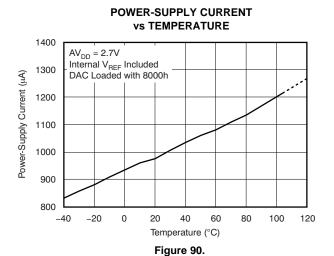


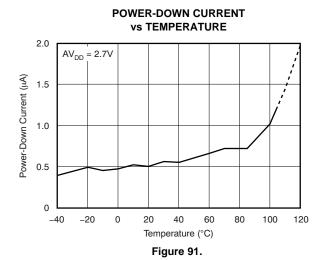
Time (400ns/div)

Figure 89.



At $T_A = +25$ °C, internal reference used, and DAC output not loaded, all DAC codes in straight binary data format, unless otherwise noted







THEORY OF OPERATION

DIGITAL-TO-ANALOG CONVERTER (DAC)

The DAC8564 architecture consists of a string DAC followed by an output buffer amplifier. Figure 92 shows a block diagram of the DAC architecture.

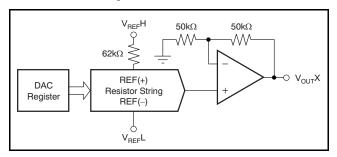


Figure 92. DAC8564 Architecture

The input coding to the DAC8564 is straight binary, so the ideal output voltage is given by Equation 1.

$$V_{OUT}X = 2 \times V_{REF}L + (V_{REF}H - V_{REF}L) \times \frac{D_{IN}}{65536}$$
 (1)

where D_{IN} = decimal equivalent of the binary code that is loaded to the DAC register; it can range from 0 to 65535. X represents channel A, B, C, or D.

RESISTOR STRING

The resistor string section is shown in Figure 93. It is simply a string of resistors, each of value *R*. The code loaded into the DAC register determines at which node on the string the voltage is tapped off to be fed into the output amplifier by closing one of the switches connecting the string to the amplifier. It is monotonic because it is a string of resistors.

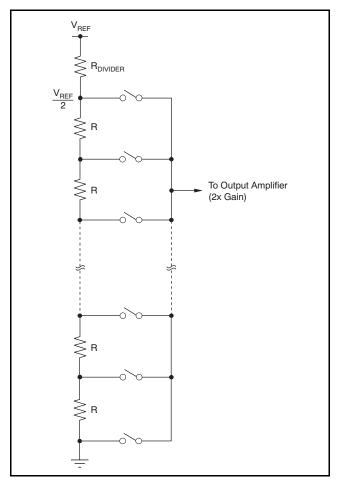


Figure 93. Resistor String

OUTPUT AMPLIFIER

The output buffer amplifier is capable of generating rail-to-rail voltages on its output, giving an output range of 0V to AV_{DD} . It is capable of driving a load of $2k\Omega$ in parallel with 1000pF to GND. The source and sink capabilities of the output amplifier can be seen in the Typical Characteristics. The slew rate is 2.2V/µs, with a full-scale settling time of 8µs with the output unloaded.



INTERNAL REFERENCE

The DAC8564 includes a 2.5V internal reference that is enabled by default. The internal reference is externally available at the $V_{REF}H/V_{REF}OUT$ pin. A minimum 100nF capacitor is recommended between the reference output and GND for noise filtering.

The internal reference of the DAC8564 is a bipolar transistor-based, precision bandgap voltage reference. Figure 94 shows the basic bandgap topology. Transistors Q₁ and Q₂ are biased such that the current density of Q_1 is greater than that of Q_2 . The difference of the two base-emitter voltages (V_{BE1} - V_{BE2}) has a positive temperature coefficient and is forced across resistor R₁. This voltage is gained up and added to the base-emitter voltage of Q2, which has a negative temperature coefficient. The resulting output voltage is virtually independent of temperature. The short-circuit current is limited by design to approximately 100mA.

Enable/Disable Internal Reference

The internal reference in the DAC8564 is enabled by default and operates in automatic mode; however, the reference can be disabled for debugging, evaluation purposes, or when using an external reference. A serial command that requires a 24-bit write sequence (see the Serial Interface section) must be used to disable the internal reference, as shown in Table 1. During the time that the internal reference is disabled, the DAC functions normally using an external reference. At this point, the internal reference is disconnected from the $V_{\rm REF}H/V_{\rm REF}OUT$ pin (3-state output). Do not attempt to drive the $V_{\rm REF}H/V_{\rm REF}OUT$ pin externally and internally at the same time indefinitely.

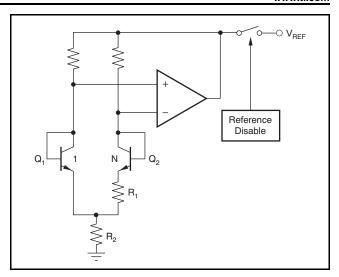


Figure 94. Simplified Schematic of the Bandgap Reference

To then enable the internal reference, either perform a power-cycle to reset the device, or write the 24-bit serial command shown in Table 2. These actions put the internal reference back into the default mode. In the default mode, the internal reference powers down automatically when all DACs power down in any of the power-down modes (see the *Power-Down Modes* section); the internal reference powers up automatically when any DAC is powered up.

The DAC8564 also provides the option of keeping the internal reference powered on all the time, regardless of the DAC(s) state (powered up or down). To keep the internal reference powered on, regardless of the DAC(s) state, write the 24-bit serial command shown in Table 3.

Table 1. Write Sequence for Disabling Internal Reference (internal reference always powered down—012000h)

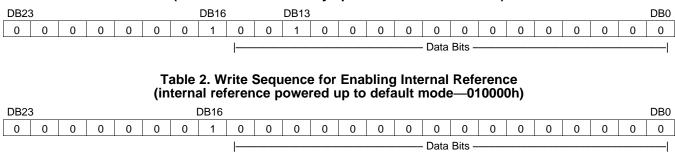
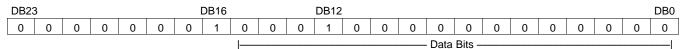


Table 3. Write Sequence for Enabling Internal Reference (internal reference always powered up—011000h)



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SERIAL INTERFACE

The DAC8564 has a 3-wire serial interface (SYNC, SCLK, and D_{IN}) compatible with SPI, QSPI, and Microwire interface standards, as well as most DSPs. See the Serial Write Operation timing diagram for an example of a typical write sequence.

The DAC8564 input shift register is 24 bits wide, consisting of eight control bits (DB23 to DB16) and 16 data bits (DB15 to DB0). All 24 bits of data are loaded into the DAC under the control of the serial clock input, SCLK. DB23 (MSB) is the first bit that is loaded into the DAC shift register, and is followed by the rest of the 24-bit word pattern, left-aligned. This configuration means that the first 24 bits of data are latched into the shift register and any further clocking of data is ignored. The DAC8564 receives all 24 bits of data and decodes the first eight bits to determine the DAC operating/control mode. The 16 bits of data that follow are decoded by the DAC to determine the equivalent analog output. The data format is straight binary with all '0's corresponding to 0V output and all '1's corresponding to full-scale output (that is, V_{REF} -1 LSB).

The write sequence begins by bringing the SYNC line low. Data from the D_{IN} line are clocked into the 24-bit shift register on each falling edge of SCLK. The serial clock frequency can be as high as 50MHz, making the DAC8564 compatible with high-speed DSPs. On the 24th falling edge of the serial clock, the last data bit is clocked into the shift register and the shift register locks. Further clocking does not change the shift register data. Once 24 bits are locked into the shift register, the eight MSBs are used as control bits and the 16 LSBs are used as data. After receiving the 24th falling clock edge, the DAC8564 decodes the eight control bits and 16 data bits to perform the required function, without waiting for a SYNC rising edge. A new write sequence starts at the next falling edge of SYNC. A rising edge of SYNC before the 24-bit sequence is complete resets the SPI interface; no data transfer occurs. After the 24th falling edge of SCLK is received, the SYNC line may be kept LOW or brought HIGH. In either case, the minimum delay time from the 24th falling SCLK edge to the next falling SYNC edge must be met in order to properly begin the next cycle. To assure the lowest power consumption of the device, care should be taken that the levels are as close to each rail as possible. Refer to the Typical Characteristics section for Figure 36, Figure 57, and Figure 79 (Supply Current vs Logic Input Voltage).

IOV_{DD} AND VOLTAGE TRANSLATORS

The IOV_{DD} pin powers the digital input structures of the DAC8564. For single-supply operation, it can be tied to AV_{DD}. For dual-supply operation, the IOV_{DD} pin provides interface flexibility with various CMOS logic families and should be connected to the logic supply of the system. Analog circuits and internal logic of the DAC8564 use AV_{DD} as the supply voltage. The external logic high inputs translate to AV_{DD} by level shifters. These level shifters use the IOV_{DD} voltage as a reference to shift the incoming logic HIGH levels to AV_{DD} . IOV_{DD} is ensured to operate from 2.7V to 5.5V regardless of the AV_{DD} voltage, assuring compatibility with various logic families. Although specified down to 2.7V, IOV_{DD} operates at as low as 1.8V with degraded timing and temperature performance. For lowest power consumption, logic V_{IH} levels should be as close as possible to IOV_{DD}, and logic V_{IL} levels should be as close as possible to GND voltages.

INPUT SHIFT REGISTER

The input shift register (SR) of the DAC8564 is 24 bits wide, as shown in Table 4, and consists of eight control bits (DB23 and DB16) and 16 data bits (DB15 to DB0). The first two control bits (DB23 and DB22) are the address match bits. The DAC8564 offers hardware-enabled addressing capability, allowing a single host to talk to up to four DAC8564s through a single SPI bus without any glue logic, enabling up to 16-channel operation. The state of DB23 should match the state of pin A1; similarly, the state of DB22 should match the state of pin A0. If there is no match, the control command and the data (DB21...DB0) are ignored by the DAC8564. That is, if there is no match, the DAC8564 is not addressed. Address matching can be overridden by the broadcast update.

Table 4. Data Input Register Format

DB23											DB12
A1	A0	LD1	LD0	0	DAC Select 1	DAC Select 0	PD0	D15	D14	D13	D12
DB11											DB0
D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0



LD1 (DB21) and LD0 (DB20) control the loading of each analog output with the specified 16-bit data value or power-down command. Bit DB19 must always be '0'. The DAC channel select bits (DB18, DB17) control the destination of the data (or power-down command) from DAC A through DAC D. The final control bit, PD0 (DB16), selects the power-down mode of the DAC8564 channels as well as the power-down mode of the internal reference.

The DAC8564 supports a number of different load commands. The load commands include broadcast commands to address all the DAC8564s on an SPI bus. The load commands are summarized as follows:

DB21 = 0 and DB20 = 0: Single-channel store. The data buffer corresponding to a DAC selected by DB18 and DB17 updates with the contents of SR data (or power-down).

DB21 = 0 and DB20 = 1: Single-channel update. The data buffer and DAC register corresponding to a DAC selected by DB18 and DB17 update with the contents of SR data (or power-down).

DB21 = 1 and DB20 = 0: Simultaneous update. A channel selected by DB18 and DB17 updates with the SR data; simultaneously, all the other channels update with previously stored data (or power-down) from data buffers.

DB21 = 1 and DB20 = 1: Broadcast update. All the DAC8564s on the SPI bus respond, regardless of address matching. If DB18 = 0, SR data are ignored and any channels from all DAC8564s update with previously stored data (or power-down). If DB18 = 1, SR data (or power-down) update any channels of all DAC8564s in the system. This broadcast update feature allows the simultaneous update of up to 16 channels.

Refer to Table 5 for more information.

Table 5. Control Matrix for the DAC8564

DB23	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DB15	DB14	DB13-DB0					
A1	A0	LD 1	LD 0	0	DAC Sel 1	DAC Sel 0	PD0	MSB	MSB-1	MSB-2LSB					
(Address	Select)										DESCRIPTION				
0/1	0/1					See Below	This address selects one of four possible devices on a single SPI data bus based on the address pin(s) state of each device.								
		0	0	0	0	0	0		Dat	ta	Write to buffer A with data				
		0	0	0	0	1	0		Dat	ta	Write to buffer B with data				
		0	0	0	1	0	0		Dat	ta	Write to buffer C with data				
		0	0	0	1	1	0		Dat	ta	Write to buffer D with data				
A0 and A	1 should	0	0	0	(00, 01, 10, or 11)				0	Write to buffer (selected by DB17 and DB18) with power-down command					
package a	correspond to the package address set via pins 13	0	1	0	(00, 01, 1	10, or 11)	0		Dat	ta	Write to buffer with data and load DAC (selected by DB17 and DB18)				
set via pir and 14		0	1	0	(00, 01, 1	10, or 11)	1	See	Table 6	0	Write to buffer with power-down command and load DAC (selected by DB17 and DB18)				
		1	0	0	(00, 01, 1	10, or 11)	0		Dat	ta	Write to buffer with data (selected by DB17 and DB18) and then load all DACs simultaneously from their corresponding buffers				
	1 0 0 (00, 01, 10,		10, or 11)	1	See Table 6 0		0	Write to buffer with power-down command (selected by DB17 and DB18) and then load all DACs simultaneously from their corresponding buffers							
					Broadcas	st Modes									
х	×	1	1	0	0	Х	x		Х		Simultaneously update all channels of all DAC8564 devices in the system with data stored in each channels data buffer				
Х	Х	1	1	0	1	Х	0	Data		Data		Data		ta	Write to all devices and load all DACs with SR data
Х	Х	1	1	0	1	X	1	See Table 6 0			Write to all devices and load all DACs with power-down command in SR				



SYNC INTERRUPT

In a normal write sequence, the SYNC line stays low for at least 24 falling edges of SCLK and the addressed DAC register updates on the 24th falling edge. However, if SYNC is brought high before the 24th falling edge, it acts as an interrupt to the write sequence; the shift register resets and the write sequence is discarded. Neither an update of the data buffer contents, DAC register contents, nor a change in the operating mode occurs (as shown in Figure 95).

POWER-ON RESET TO ZERO-SCALE

The DAC8564 contains a power-on reset circuit that controls the output voltage during power-up. On power-up, the DAC registers are filled with zeros and the output voltages are set to zero-scale; they remain that way until a valid write sequence and load command are made to the respective DAC channel. The power-on reset is useful in applications where it is important to know the state of the output of each DAC while the device is in the process of powering up.

No device pin should be brought high before power is applied to the device. The internal reference is powered on by default and remains that way until a valid reference-change command is executed.

LDAC FUNCTIONALITY

The DAC8564 offers both a software and hardware simultaneous update function. The DAC double-buffered architecture has been designed so that new data can be entered for each DAC without disturbing the analog outputs.

DAC8564 data updates are synchronized with the falling edge of the 24th SCLK cycle, which follows a falling edge of SYNC. For such synchronous updates. the LDAC pin is not required and it must be connected to GND permanently. The LDAC pin is used as a positive edge triggered timing signal for asynchronous DAC updates. To do an LDAC operation, single-channel store(s) should be done (loading DAC buffers) by setting LD0 and LD1 to '0'. Multiple single-channel updates can be done in order to set different channel buffers to desired values and then make a rising edge on LDAC. Data buffers of all channels must be loaded with desired data before an LDAC rising edge. After a low-to-high LDAC transition, all DACs are simultaneously updated with the contents of the corresponding data buffers. If the contents of a data buffer are not changed by the serial interface, the corresponding DAC output remains unchanged after the LDAC trigger.

ENABLE PIN

For normal operation, the enable pin must be driven to a logic low. If the enable pin is driven high, the DAC85 $\underline{64}$ stops listening to the serial port. However, SCLK, $\overline{\text{SYNC}}$, and D_{IN} must not be kept floating, but must be at some logic level. This feature can be useful for applications that share the same serial port.

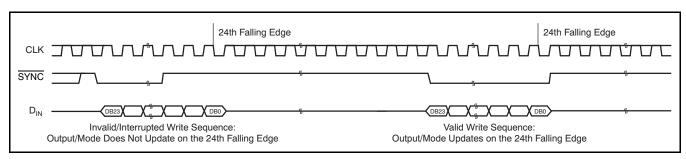


Figure 95. SYNC Interrupt Facility



POWER-DOWN MODES

The DAC8564 has two separate sets of power-down commands. One set is for the DAC channels and the other set is for the internal reference. For more information on powering down the reference, see the *Enable/Disable Internal Reference* section.

DAC Power-Down Commands

The DAC8564 uses four modes of operation. These modes are accessed by setting three bits (PD2, PD1, and PD0) in the shift register. Table 6 shows how to control the operating mode with data bits PD0 (DB16), PD1 (DB15), and PD2 (DB14).

Table 6. DAC Operating Modes

PD0 (DB16)	PD1 (DB15)	PD2 (DB14)	DAC OPERATING MODES
0	Х	Х	Normal operation
1	0	1	Output typically 1kΩ to GND
1	1	0	Output typically 100 kΩ to GND
1	1	1	Output high-impedance

The DAC8564 treats the power-down condition as data; all the operational modes are still valid for power-down. It is possible to broadcast a power-down condition to all the DAC8564s in a system; it is also possible to simultaneously power-down a channel while updating data on other channels.

When the PD0 bit is set to '0', the device works normally with its typical current consumption of 1mA at 5.5V with an input code = 32768. The reference current is included with the operation of all four

DACs. However, for the three power-down modes, the supply current falls to $1.3\mu A$ at 5.5V ($0.5\mu A$ at 3.6V). Not only does the supply current fall, but the output stage also switches internally from the output of the amplifier to a resistor network of known values.

The advantage of this switching is that the output impedance of the device is known while it is in power-down mode. As described in Table 6, there are three different power-down options. V_{OUT} can be connected internally to GND through a $1k\Omega$ resistor, a $100k\Omega$ resistor, or open circuited (High-Z). The output stage is shown in Figure 96. In other words, DB16, DB15, and DB14 = '111' represent a power-down condition with Hi-Z output impedance for a selected channel. '101' represents a power-down condition with $1k\Omega$ output impedance, and '110' represents a power-down condition with $100k\Omega$ output impedance.

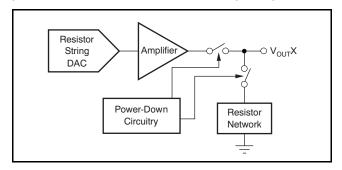


Figure 96. Output Stage During Power-Down

All analog channel circuitries are shut down when the power-down mode is exercised. However, the contents of the DAC register are unaffected when in power down. The time required to exit power-down is typically 2.5 μ s for $V_{DD}=5V$, and 5 μ s for $V_{DD}=3V$. See the Typical Characteristics for more information.



OPERATING EXAMPLES: DAC8564

For the following examples, ensure that DAC pins A0 and A1 are both connected to ground. Pins A0 and A1 must always match data bits DB22 and DB23 within the SPI write sequence/protocol. X = don't care. Value can be either '0' or '1'.

Example 1: Write to Data Buffer A Through Buffer D; Load DAC A Through DAC D Simultaneously

1st: Write to data buffer A:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	0	0	0	0	0	D15	D14	D13	D12	D11-D0

2nd: Write to data buffer B:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	0	0	0	1	0	D15	D14	D13	D12	D11-D0

3rd: Write to data buffer C:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	0	0	1	0	0	D15	D14	D13	D12	D11-D0

4th: Write to data buffer D and simultaneously update all DACs:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	1	0	0	1	1	0	D15	D14	D13	D12	D11-D0

The DAC A, DAC B, DAC C, and DAC D analog outputs simultaneously settle to the specified values upon completion of the 4th write sequence. (The DAC voltages update simultaneously after the 24th SCLK falling edge of the fourth write cycle).

Example 2: Load New Data to DAC A Through DAC D Sequentially

• 1st: Write to data buffer A and load DAC A: DAC A output settles to specified value upon completion:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	1	0	0	0	0	D15	D14	D13	D12	D11-D0

2nd: Write to data buffer B and load DAC B: DAC B output settles to specified value upon completion:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	1	0	0	1	0	D15	D14	D13	D12	D11-D0

3rd: Write to data buffer C and load DAC C: DAC C output settles to specified value upon completion:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	1	0	1	0	0	D15	D14	D13	D12	D11-D0

• 4th: Write to data buffer D and load DAC D: DAC D output settles to specified value upon completion:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	1	0	1	1	0	D15	D14	D13	D12	D11-D0

After completion of each write cycle, DAC analog output settles to the voltage specified.



Example 3: Power-Down DAC A and DAC B to $1k\Omega$ and Power-Down DAC C and DAC D to $100k\Omega$ Simultaneously

• 1st: Write power-down command to data buffer A: DAC A to $1k\Omega$.

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0	
0	0	0	0	0	0	0	1	0	1	Χ	Χ	Х	

2nd: Write power-down command to data buffer B: DAC B to 1kΩ.

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	0	0	0	1	1	0	1	Х	Х	X

3rd: Write power-down command to data buffer C: DAC C to 100kΩ.

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0	
0	0	0	0	0	1	0	1	1	0	Χ	Х	X	

4th: Write power-down command to data buffer D: DAC D to 100kΩ and simultaneously update all DACs.

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	1	0	0	1	1	1	1	0	Х	Х	X

The DAC A, DAC B, DAC C, and DAC D analog outputs simultaneously power-down to each respective specified mode upon completion of the fourth write sequence.

Example 4: Power-Down DAC A Through DAC D to High-Impedance Sequentially

1st: Write power-down command to data buffer A and load DAC A: DAC A output = Hi-Z:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	1	0	0	0	1	1	1	Х	Х	X

2nd: Write power-down command to data buffer B and load DAC B: DAC B output = Hi-Z:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	1	0	0	1	1	1	1	Х	Х	X

3rd: Write power-down command to data buffer C and load DAC C: DAC C output = Hi-Z:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	1	0	1	0	1	1	1	Х	Х	X

• 4th: Write power-down command to data buffer D and load DAC D: DAC D output = Hi-Z:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	1	0	1	1	1	1	1	Х	Х	X

The DAC A, DAC B, DAC C, and DAC D analog outputs sequentially power-down to high-impedance upon completion of the first, second, third, and fourth write sequences, respectively.



Example 5: Power-Down All Channels Simultaneously while Reference is Always Powered Up

1st: Write sequence for enabling the DAC8564 internal reference all the time:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	0	0	0	0	1	0	0	0	1	X

2nd: Write sequence to power-down all DACs to high-impedance:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	1	1	0	1	0	1	1	1	Χ	Х	X

The DAC A, DAC B, DAC C, and DAC D analog outputs sequentially power-down to high-impedance upon completion of the first and second write sequences, respectively.

Example 6: Write a Specific Value to All DACs while Reference is Always Powered Down

• 1st: Write sequence for disabling the DAC8564 internal reference all the time (after this sequence, the DAC8564 requires an external reference source to function):

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	0	0	0	0	1	0	0	1	0	X

2nd: Write sequence to write specified data to all DACs:

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	1	1	0	1	0	0	D15	D14	D13	D12	D11-D0

The DAC A, DAC B, DAC C, and DAC D analog outputs simultaneously settle to the specified values upon completion of the fourth write sequence. (The DAC voltages update simultaneously after the 24th SCLK falling edge of the fourth write cycle). Reference is always powered-down.

Example 7: Write a Specific Value to DAC A, while Reference is Placed in Default Mode and All Other DACs are Powered Down to High-Impedance

• 1st: Write sequence for placing the DAC8564 internal reference into default mode. Alternately, this step can be replaced by performing a power-on reset (see the *Power-On Reset* section):

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	0	0	0	0	0	1	0	0	0	0	X

• 2nd: Write sequence to power-down all DACs to high-impedance (after this sequence, the DAC8564 internal reference powers down automatically):

DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
0	0	1	1	0	1	0	1	1	1	X	Х	X

 3rd: Write sequence to power-up DAC A to a specified value (after this sequence, the DAC8564 internal reference powers up automatically):

	DB23 (A1)	DB22 (A0)	DB21 (LD1)	DB20 (LD0)	DB19	DB18 (DAC Sel 1)	DB17 (DAC Sel 0)	DB16 (PD0)	DB15	DB14	DB13	DB12	DB11-DB0
Ī	0	0	0	1	0	0	0	0	D15	D14	D13	D12	D11-D0

The DAC B, DAC C, and DAC D analog outputs simultaneously power-down to high-impedance, and DAC A settles to the specified value upon completion.



APPLICATION INFORMATION

INTERNAL REFERENCE

The internal reference of the DAC8564 does not require an external load capacitor for stability because it is stable with any capacitive load. However, for improved noise performance, an external load capacitor of 150nF or larger connected to the $V_{\text{REF}}\text{H/V}_{\text{REF}}\text{OUT}$ output is recommended. Figure 97 shows the typical connections required for operation of the DAC8564 internal reference. A supply bypass capacitor at the AV_{DD} input is also recommended.

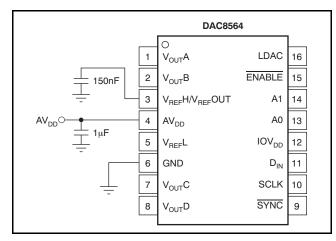


Figure 97. Typical Connections for Operating the DAC8564 Internal Reference

Supply Voltage

The internal reference features an extremely low dropout voltage. It can be operated with a supply of only 5mV above the reference output voltage in an unloaded condition. For loaded conditions, refer to the *Load Regulation* section. The stability of the internal reference with variations in supply voltage (line regulation, dc PSRR) is also exceptional. Within the specified supply voltage range of 2.7V to 5.5V, the variation at $V_{REF}H/V_{REF}OUT$ is less than $10\mu V/V$; see the Typical Characteristics.

Temperature Drift

The internal reference is designed to exhibit minimal drift error, defined as the change in reference output voltage over varying temperature. The drift is calculated using the *box* method described by Equation 2:

Drift Error =
$$\left[\frac{V_{REF_MAX} - V_{REF_MIN}}{V_{REF} \times T_{RANGE}} \right] \times 10^6 \text{ (ppm/°C)}$$
 (2)

Where:

 $V_{\text{REF_MAX}}$ = maximum reference voltage observed within temperature range T_{RANGE} .

 $V_{\text{REF_MIN}}$ = minimum reference voltage observed within temperature range T_{RANGE} .

 $V_{REF} = 2.5V$, target value for reference output voltage.

The internal reference (grades C and D) features an exceptional typical drift coefficient of 2ppm/°C from –40°C to +120°C. Characterizing a large number of units, a maximum drift coefficient of 5ppm/°C (grades C and D) is observed. Temperature drift results are summarized in the Typical Characteristics.

Noise Performance

Typical 0.1Hz to 10Hz voltage noise can be seen in Figure 8, Internal Reference Noise. Additional filtering can be used to improve output noise levels, although care should be taken to ensure the output impedance does not degrade the ac performance. The output noise spectrum at $V_{REF}H/V_{REF}OUT$ without any external components is depicted in Figure 7, Internal Reference Noise Density vs Frequency. Another noise density spectrum is also shown in Figure 7. This spectrum was obtained using a 4.8 μ F load capacitor at $V_{REF}H/V_{REF}OUT$ for noise filtering. Internal reference noise impacts the DAC output noise; see the DAC Noise Performance section for more details.

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Load Regulation

Load regulation is defined as the change in reference output voltage as a result of changes in load current. The load regulation of the internal reference is measured using force and sense contacts as shown in Figure 98. The force and sense lines reduce the impact of contact and trace resistance, resulting in accurate measurement of the load regulation contributed solely by the internal reference. Measurement results are summarized in the Typical Characteristics. Force and sense lines should be used for applications that require improved load regulation.

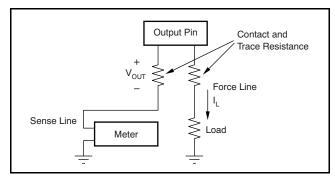


Figure 98. Accurate Load Regulation of the DAC8564 Internal Reference

Long-Term Stability

Long-term stability/aging refers to the change of the output voltage of a reference over a period of months or years. This effect lessens as time progresses (see Figure 6, the typical long-term stability curve). The typical drift value for the internal reference is 50ppm from 0 hours to 1900 hours. This parameter is characterized by powering-up and measuring 20 units at regular intervals for a period of 1900 hours.

Thermal Hysteresis

Thermal hysteresis for a reference is defined as the change in output voltage after operating the device at +25°C, cycling the device through the operating temperature range, and returning to +25°C. Hysteresis is expressed by Equation 3:

$$V_{HYST} = \left(\frac{\left|V_{REF_PRE} - V_{REF_POST}\right|}{V_{REF_NOM}}\right) \times 10^{6} \text{ (ppm/°C)}$$
(3)

Where:

 V_{HYST} = thermal hysteresis.

V_{REF_PRE} = output voltage measured at +25°C pre-temperature cycling.

V_{REF_POST} = output voltage measured after the device cycles through the temperature range of -40°C to +120°C, and returns to +25°C.

DAC NOISE PERFORMANCE

Typical noise performance for the DAC8564 with the internal reference enabled is shown in Figure 54 to Figure 56. Output noise spectral density at the V_{OUT} pin versus frequency is depicted in Figure 54 for full-scale, midscale, and zero-scale input codes. The typical noise density for midscale code is $120nV/\sqrt{Hz}$ at 1kHz and $100nV/\sqrt{Hz}$ at 1MHz. High-frequency noise can be improved by filtering the reference noise as shown in Figure 55, where a 4.8 μ F load capacitor is connected to the $V_{REF}H/V_{REF}OUT$ pin and compared to the no-load condition. Integrated output noise between 0.1Hz and 10Hz is close to $6\mu V_{PP}$ (midscale), as shown in Figure 56.



BIPOLAR OPERATION USING THE DAC8564

The DAC8564 is designed for single-supply operation, but a bipolar output range is also possible using the circuit in either Figure 99 or Figure 100. The circuit shown gives an output voltage range of $\pm V_{REF}$. Rail-to-rail operation at the amplifier output is achievable using an OPA703 as the output amplifier.

The output voltage for any input code can be calculated with Equation 4:

$$V_{O} = \left[V_{REF} \times \left(\frac{D}{65536}\right) \times \left(\frac{R_{1} + R_{2}}{R_{1}}\right) - V_{REF} \times \left(\frac{R_{2}}{R_{1}}\right)\right]$$
(4)

where D represents the input code in decimal (0-65535).

With $V_{REF}H = 5V$, $R_1 = R_2 = 10k\Omega$.

$$V_{O} = \left(\frac{10 \times D}{65536}\right) - 5V \tag{5}$$

This result has an output voltage range of ±5V with 0000h corresponding to a -5V output and FFFFh corresponding to a +5V output, as shown in Figure 99. Similarly, using the internal reference, a ±2.5V output voltage range can be achieved, as Figure 100 shows.

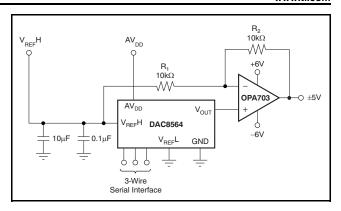


Figure 99. Bipolar Output Range Using External Reference at 5V

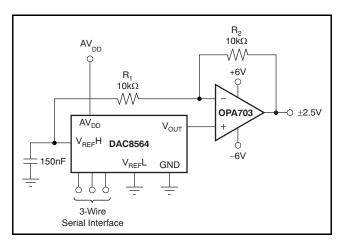


Figure 100. Bipolar Output Range Using Internal Reference



MICROPROCESSOR INTERFACING

DAC SPI Interfacing

Care must be taken with the digital control signals that are applied directly to the DAC, especially with the SYNC pin. The SYNC pin must not be toggled without having a full SCLK pulse in between. If this condition is violated, the SPI interface locks up in an erroneous state, causing the DAC to behave incorrectly and have errors. The DAC can be recovered from this faulty state by writing a valid SPI command or using the SYNC pin correctly; communication will then be restored. Avoid glitches and transients on the SYNC line to ensure proper operation.

DAC8564 to an 8051 Interface

Figure 101 shows a serial interface between the DAC8564 and a typical 8051-type microcontroller. The setup for the interface is as follows: TXD of the 8051 drives SCLK of the DAC8564, while RXD drives the serial data line of the device. The SYNC signal is derived from a bit-programmable pin on the port of the 8051; in this case, port line P3.3 is used. When data are to be transmitted to the DAC8564, P3.3 is taken low. The 8051 transmits data in 8-bit bytes; thus, only eight falling clock edges occur in the transmit cycle. To load data to the DAC, P3.3 is left low after the first eight bits are transmitted; then, a second write cycle is initiated to transmit the second byte of data. P3.3 is taken high following the completion of the third write cycle. The 8051 outputs the serial data in a format that has the LSB first. The DAC8564 requires its data with the MSB as the first bit received. The 8051 transmit routine must therefore take this requirement into account, and mirror the data as needed.

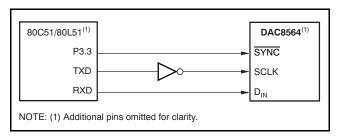


Figure 101. DAC8564 to 80C51/80L51 Interface

DAC8564 to Microwire Interface

Figure 102 shows an interface between the DAC8564 and any Microwire-compatible device. Serial data are shifted out on the falling edge of the serial clock and are clocked into the DAC8564 on the rising edge of the SK signal.

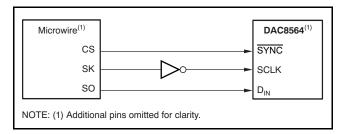


Figure 102. DAC8564 to Microwire Interface

DAC8564 to 68HC11 Interface

Figure 103 shows a serial interface between the DAC8564 and the 68HC11 microcontroller. SCK of the 68HC11 drives the SCLK of the DAC8564, while the MOSI output drives the serial data line of the DAC. The SYNC signal derives from a port line (PC7), similar to the 8051 diagram.

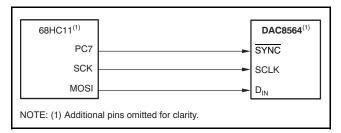


Figure 103. DAC8564 to 68HC11 Interface

The 68HC11 should be configured so that its CPOL bit is '0' and its CPHA bit is '1'. This configuration causes data appearing on the MOSI output to be valid on the falling edge of SCK. When data are being transmitted to the DAC, the SYNC line is held low (PC7). Serial data from the 68HC11 are transmitted in 8-bit bytes with only eight falling clock edges occurring in the transmit cycle. (Data are transmitted MSB first.) In order to load data to the DAC8564, PC7 is left low after the first eight bits are transferred; then, a second and third serial write operation are performed to the DAC. PC7 is taken high at the end of this procedure.



LAYOUT

A precision analog component requires careful layout, adequate bypassing, and clean, well-regulated power supplies.

The DAC8564 offers single-supply operation, and is often used in close proximity with digital logic, microcontrollers, microprocessors, and digital signal processors. The more digital logic present in the design and the higher the switching speed, the more difficult it is to keep digital noise from appearing at the output.

As a result of the single ground pin of the DAC8564, all return currents (including digital and analog return currents for the DAC) must flow through a single point. Ideally, GND would be connected directly to an analog ground plane. This plane would be separate from the ground connection for the digital components until they were connected at the power-entry point of the system.

The power applied to V_{DD} should be well-regulated and low noise. Switching power supplies and dc/dc converters often have high-frequency glitches or spikes riding on the output voltage. In addition, digital components can create similar high-frequency spikes as their internal logic switches states. This noise can easily couple into the DAC output voltage through various paths between the power connections and analog output.

As with the GND connection, V_{DD} should be connected to a power-supply plane or trace that is separate from the connection for digital logic until they are connected at the power-entry point. In addition, a 1µF to 10µF capacitor and 0.1µF bypass capacitor are strongly recommended. In some situations, additional bypassing may be required, such as a 100µF electrolytic capacitor or even a Pi filter made up of inductors and capacitors—all designed to essentially low-pass filter the supply and remove the high-frequency noise.



PARAMETER DEFINITIONS

With the increased complexity of many different specifications listed in product data sheets, this section summarizes selected specifications related to digital-to-analog converters.

STATIC PERFORMANCE

Static performance parameters are specifications such as differential nonlinearity (DNL) or integral nonlinearity (INL). These are dc specifications and provide information on the accuracy of the DAC. They are most important in applications where the signal changes slowly and accuracy is required.

Resolution

Generally, the DAC resolution can be expressed in different forms. Specifications such as IEC 60748-4 recognize the numerical, analog, and relative resolution. The numerical resolution is defined as the number of digits in the chosen numbering system necessary to express the total number of steps of the transfer characteristic, where a step represents both a digital input code and the corresponding discrete analogue output value. The most commonly-used definition of resolution provided in data sheets is the numerical resolution expressed in bits.

Least Significant Bit (LSB)

The least significant bit (LSB) is defined as the smallest value in a binary coded system. The value of the LSB can be calculated by dividing the full-scale output voltage by 2^n , where n is the resolution of the converter.

Most Significant Bit (MSB)

The most significant bit (MSB) is defined as the largest value in a binary coded system. The value of the MSB can be calculated by dividing the full-scale output voltage by 2. Its value is one-half of full-scale.

Relative Accuracy or Integral Nonlinearity (INL)

Relative accuracy or integral nonlinearity (INL) is defined as the maximum deviation between the real transfer function and a straight line passing through the endpoints of the ideal DAC transfer function. DNL is measured in LSBs.

Differential Nonlinearity (DNL)

Differential nonlinearity (DNL) is defined as the maximum deviation of the real LSB step from the ideal 1LSB step. Ideally, any two adjacent digital codes correspond to output analog voltages that are exactly one LSB apart. If the DNL is less than 1LSB, the DAC is said to be monotonic.

Full-Scale Error

Full-scale error is defined as the deviation of the real full-scale output voltage from the ideal output voltage while the DAC register is loaded with the full-scale code (0xFFFF). Ideally, the output should be $V_{DD}-1$ LSB. The full-scale error is expressed in percent of full-scale range (%FSR).

Offset Error

The offset error is defined as the difference between actual output voltage and the ideal output voltage in the linear region of the transfer function. This difference is calculated by using a straight line defined by two codes (code 485 and 64714). Since the offset error is defined by a straight line, it can have a negative or positive value. Offset error is measured in mV.

Zero-Code Error

The zero-code error is defined as the DAC output voltage, when all '0's are loaded into the DAC register. Zero-scale error is a measure of the difference between actual output voltage and ideal output voltage (0V). It is expressed in mV. It is primarily caused by offsets in the output amplifier.

Gain Error

Gain error is defined as the deviation in the slope of the real DAC transfer characteristic from the ideal transfer function. Gain error is expressed as a percentage of full-scale range (%FSR).

Full-Scale Error Drift

Full-scale error drift is defined as the change in full-scale error with a change in temperature. Full-scale error drift is expressed in units of %FSR/°C.

Offset Error Drift

Offset error drift is defined as the change in offset error with a change in temperature. Offset error drift is expressed in $\mu V/^{\circ}C$.

Zero-Code Error Drift

Zero-code error drift is defined as the change in zero-code error with a change in temperature. Zero-code error drift is expressed in $\mu V/^{\circ}C$.



Gain Temperature Coefficient

The gain temperature coefficient is defined as the change in gain error with changes in temperature. The gain temperature coefficient is expressed in ppm of FSR/°C.

Power-Supply Rejection Ratio (PSRR)

Power-supply rejection ratio (PSRR) is defined as the ratio of change in output voltage to a change in supply voltage for a full-scale output of the DAC. The PSRR of a device indicates how the output of the DAC is affected by changes in the supply voltage. PSRR is measured in decibels (dB).

Monotonicity

Monotonicity is defined as a slope whose sign does not change. If a DAC is monotonic, the output changes in the same direction or remains at least constant for each step increase (or decrease) in the input code.

DYNAMIC PERFORMANCE

Dynamic performance parameters are specifications such as settling time or slew rate, which are important in applications where the signal rapidly changes and/or high frequency signals are present.

Slew Rate

The output slew rate (SR) of an amplifier or other electronic circuit is defined as the maximum rate of change of the output voltage for all possible input signals.

$$SR = \max \left[\left| \frac{\Delta V_{OUT}(t)}{\Delta t} \right| \right]$$

Where $\Delta V_{OUT}(t)$ is the output produced by the amplifier as a function of time t.

Output Voltage Settling Time

Settling time is the total time (including slew time) for the DAC output to settle within an error band around its final value after a change in input. Settling times are specified to within $\pm 0.003\%$ (or whatever value is specified) of full-scale range (FSR).

Code Change/Digital-to-Analog Glitch Energy

Digital-to-analog glitch impulse is the impulse injected into the analog output when the input code in the DAC register changes state. It is normally specified as the area of the glitch in nanovolts-second (nV-s), and is measured when the digital input code is changed by 1LSB at the major carry transition.

Digital Feedthrough

Digital feedthrough is defined as impulse seen at the output of the DAC from the digital inputs of the DAC. It is measured when the DAC output is not updated. It is specified in nV-s, and measured with a full-scale code change on the data bus; that is, from all '0's to all '1's and vice versa.

Channel-to-Channel DC Crosstalk

Channel-to-channel dc crosstalk is defined as the dc change in the output level of one DAC channel in response to a change in the output of another DAC channel. It is measured with a full-scale output change on one DAC channel while monitoring another DAC channel remains at midscale. It is expressed in LSB.

Channel-to-Channel AC Crosstalk

AC crosstalk in a multi-channel DAC is defined as the amount of ac interference experienced on the output of a channel at a frequency (f) (and its harmonics), when the output of an adjacent channel changes its value at the rate of frequency (f). It is measured with one channel output oscillating with a sine wave of 1kHz frequency, while monitoring the amplitude of 1kHz harmonics on an adjacent DAC channel output (kept at zero scale). It is expressed in dB.

Signal-to-Noise Ratio (SNR)

Signal-to-noise ratio (SNR) is defined as the ratio of the root mean-squared (RMS) value of the output signal divided by the RMS values of the sum of all other spectral components below one-half the output frequency, not including harmonics or dc. SNR is measured in dB.

Total Harmonic Distortion (THD)

Total harmonic distortion + noise is defined as the ratio of the RMS values of the harmonics and noise to the value of the fundamental frequency. It is expressed in a percentage of the fundamental frequency amplitude at sampling rate $f_{\rm S}$.

Spurious-Free Dynamic Range (SFDR)

Spurious-free dynamic range (SFDR) is the usable dynamic range of a DAC before spurious noise interferes or distorts the fundamental signal. SFDR is the measure of the difference in amplitude between the fundamental and the largest harmonically or non-harmonically related spur from dc to the full Nyquist bandwidth (half the DAC sampling rate, or f_S/2). A spur is any frequency bin on a spectrum analyzer, or from a Fourier transform, of the analog output of the DAC. SFDR is specified in decibels relative to the carrier (dBc).

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Signal-to-Noise plus Distortion (SINAD)

SINAD includes all the harmonic and outstanding spurious components in the definition of output noise power in addition to quantizing any internal random noise power. SINAD is expressed in dB at a specified input frequency and sampling rate, f_S.

DAC Output Noise Density

Output noise density is defined as internally-generated random noise. Random noise is characterized as a spectral density (nV/ $\sqrt{\text{Hz}}$). It is measured by loading the DAC to midscale and measuring noise at the output.

DAC Output Noise

DAC output noise is defined as any voltage deviation of DAC output from the desired value (within a particular frequency band). It is measured with a DAC channel kept at midscale while filtering the output voltage within a band of 0.1Hz to 10Hz and measuring its amplitude peaks. It is expressed in terms of peak-to-peak voltage (V_{DD}).

Full-Scale Range (FSR)

Full-scale range (FSR) is the difference between the maximum and minimum analog output values that the DAC is specified to provide; typically, the maximum and minimum values are also specified. For an *n*-bit DAC, these values are usually given as the values matching with code 0 and 2ⁿ.



REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision C (September 2010) to Revision D
•	Changed Output Voltage parameter min/max values from 2.4995 and 2.5005 to 2.4975 and 2.5025, respectively
С	hanges from Revision B (March 2008) to Revision C Page
•	Changed t ₂ minimum values in the <i>Timing Requirements</i> table
•	Added DAC SPI Interfacing subsection to Microprocessor Interfacing section

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7-Oct-2025

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
DAC8564IAPW	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	DAC 8564
DAC8564IAPW.A	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	DAC 8564
DAC8564IAPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	DAC 8564
DAC8564IAPWR.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	DAC 8564
DAC8564IBPW	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	DAC 8564 B
DAC8564IBPW.A	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	DAC 8564 B
DAC8564ICPW	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	Call TI	Level-1-260C-UNLIM	-40 to 105	DAC 8564
DAC8564ICPW.A	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	Call TI	Level-1-260C-UNLIM	-40 to 105	DAC 8564
DAC8564ICPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	Call TI	Level-1-260C-UNLIM	-40 to 105	DAC 8564
DAC8564ICPWR.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	Call TI	Level-1-260C-UNLIM	-40 to 105	DAC 8564
DAC8564IDPW	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	Call TI	Level-1-260C-UNLIM	-40 to 105	DAC 8564 D
DAC8564IDPW.A	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	Call TI	Level-1-260C-UNLIM	-40 to 105	DAC 8564 D
DAC8564IDPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	Call TI	Level-1-260C-UNLIM	-40 to 105	DAC 8564 D
DAC8564IDPWR.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	Call TI	Level-1-260C-UNLIM	-40 to 105	DAC 8564 D



PACKAGE OPTION ADDENDUM

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- (1) Status: For more details on status, see our product life cycle.
- (2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

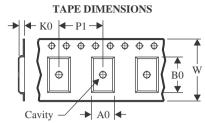
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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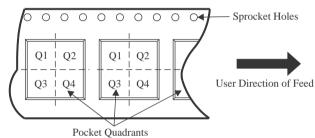
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

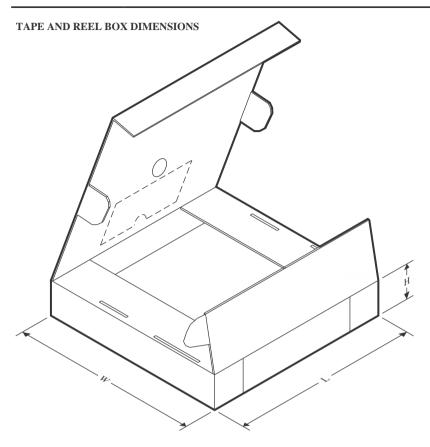


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DAC8564IAPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
DAC8564ICPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
DAC8564IDPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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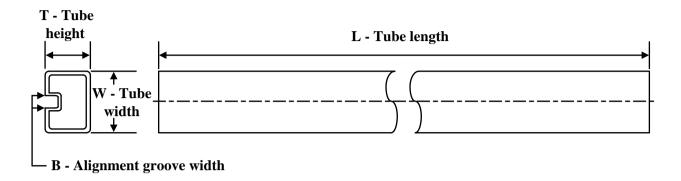
*All dimensions are nominal

Device	evice Package Type Package Drawing		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DAC8564IAPWR	TSSOP	PW	16	2000	350.0	350.0	43.0
DAC8564ICPWR	TSSOP	PW	16	2000	350.0	350.0	43.0
DAC8564IDPWR	TSSOP	PW	16	2000	350.0	350.0	43.0

PACKAGE MATERIALS INFORMATION

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TUBE

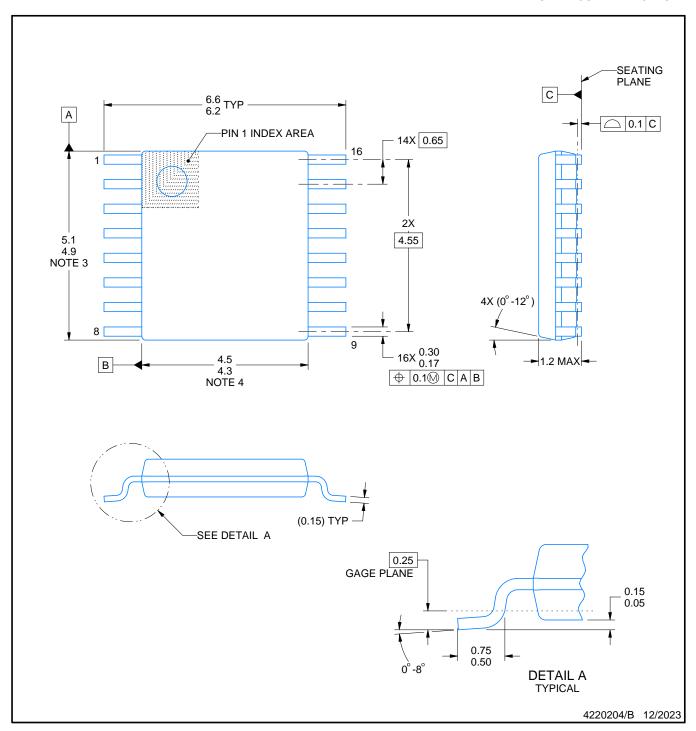


*All dimensions are nominal

Device	Device Package Name		Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
DAC8564IAPW	PW	TSSOP	16	90	530	10.2	3600	3.5
DAC8564IAPW.A	PW	TSSOP	16	90	530	10.2	3600	3.5
DAC8564IBPW	PW	TSSOP	16	90	530	10.2	3600	3.5
DAC8564IBPW.A	PW	TSSOP	16	90	530	10.2	3600	3.5
DAC8564ICPW	PW	TSSOP	16	90	530	10.2	3600	3.5
DAC8564ICPW.A	PW	TSSOP	16	90	530	10.2	3600	3.5
DAC8564IDPW	PW	TSSOP	16	90	530	10.2	3600	3.5
DAC8564IDPW.A	PW	TSSOP	16	90	530	10.2	3600	3.5



SMALL OUTLINE PACKAGE



NOTES:

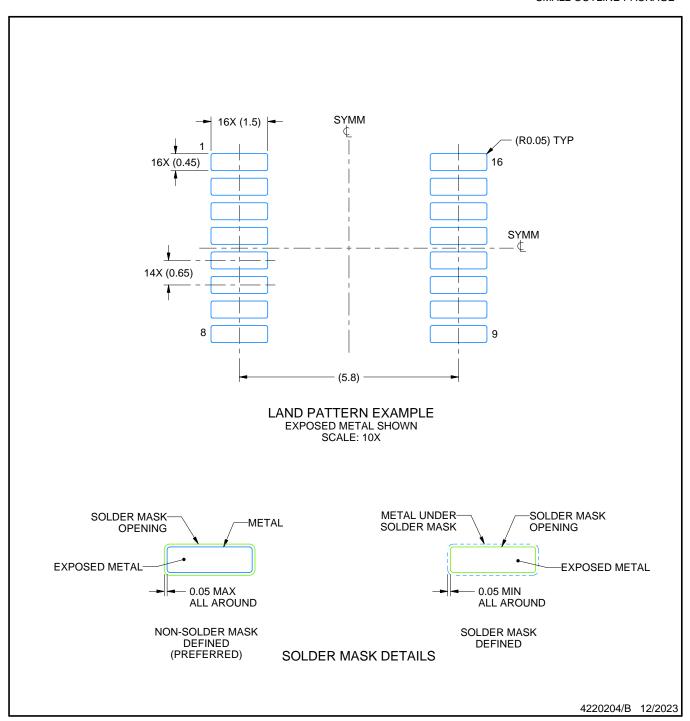
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE

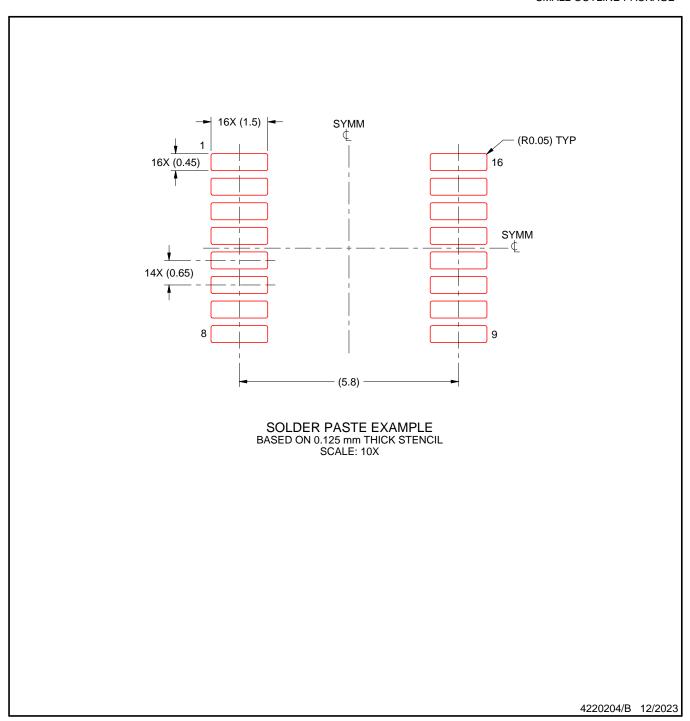


NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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